

A.HE83121 Introduction

HE83121 is a member of Jess Tech HE8000 series 8-bit CMOS micro-controller. This IC provides 320 dots of LCD driver and 16-bit I/O pin. Besides, it built-in one internal Op-Amp, one 7-bit D/A converter and one PWM output module to provide a speech output interface. Use the built-in 128K ROM can store around 40 seconds of speech data. It is suitable for the application in digital meter, stopwatch, thermometer and so on.

The HE83121 provides a very simple and effective instruction set, each instruction byte occupies only 1.5 clock cycle time, therefore, it is suitable to apply in the high performance systems.

B.HE83121 Features

- Operating Voltage: 2.4V – 5.2V
- Operation frequency Range: DC ~ 8MHz @ 5.0V
DC ~ 4MHz @ 2.4V
- ROM size: 128K Bytes
- RAM size: 256 Bytes
- Dual Clock: Normal(Fast) clock: 32.768K ~ 8MHz
Slow clock: 32.768KHz
- Operating Mode: DUAL , FAST , SLOW , IDLE , SLEEP
- Built-in WATCH DOG TIMER
- 12-bit bi-directional I/O pins, PUSH-PULL or OPEN DRAIN output selected by mask option
- Built-in an internal Op-Amp
- 320 dots of LCD driver, (A 、 B TYPE)
- Built-in one 7-bit D/A Converter
- Built-in a PWM output circuit
- Provides two internal and two external interrupt
- Provides two 16-bit timer (no time base)
- Instruction Set : 32 Instructions, 4 types of Addressing Mode, 2 individual Pointer for ROM (17-bit) and RAM (8-bit) table access.

C.HE83121 Application

- Power Speech Controller provides around 40 seconds of speech time and 320 dots of LCD
- Digital meter, stopwatch, thermometer, and LCD games
- Interface to Light, Sound, Temperature and Humidity sensor for controlling application.

D. Pin Assignment

Pin	Pin Name	I/O	Function	Description
68 67	FXI, FXO	B, O	External Fast Clock pin. To connect the Crystal or R,C oscillation to generate 32.768KHz ~ 8MHz system clock.	Mask Option settings : MO_FCK/SCKN=00 : Slow Clock only 01 : Illegal 10 : Dual Clock 11 : Fast Clock only MO_FOSCE=0 : Internal fast oscillation 1 : External fast oscillation MO_FXTAL=0 : R,C oscillation for Fast Clock 1 : Crystal oscillation for Fast Clock MO_SXTAL=0 : R,C oscillation for 32.768K Clock 1 : X'tal oscillation for 32.768K Clock Program the value of OP1 and OP2 to change the operating modes (Normal, Slow, Idle and Sleep). In Dual Clock mode, the system runs in Fast Clock, only the Timer 1 use the 32.768K clock source.
71 70	SXI, SXO	I, O	External Slow Clock pin. To connect the 32.768KHz oscillator to generate the stable frequency for Slow Mode, and provide IC LCD display, Timer clock source.	
66	RSTP_N	I	System reset signal	Pull this pin to low level to reset the system. Besides, Select the Mask Option (MO_PORE=1) to enable the IC internal Power-on Reset function. In addition, the MO_WDTE is used for Watch Dog Timer setting : MO_WDTE =0 : Disable Watch Dog Timer =1 : Enable Watch Dog Timer
69	TSTP_P	I	Test Pin.	Please bond this pin and add a test point on PCB for debugging. Leave this pin floating is OK.
81,82 83,1	PRTC[3:0]	B	Port C bi-directional I/O pin (4 pins).	Mask Option MO_CPP[3:0] to preset the output type: MO_CPP=1 : Push-pull output ; = 0 : Open-drain output. When assigned the port to input pin, send a '1' and read the result to get the input value.
73.. 80	PRTD[7:0]	B	Port D bi-directional I/O pin, (8 pins). PRTD[7:2] is also a Wake-up pin and PRTD[7:6] is used for interrupt input pin.	Mask Option MO_DPP[7:0] to preset the output type: MO_DPP=1 : Push-pull output ; 0 : Open-drain output. When assigned the port to input pin, send a '1' and read the result to get the input value.
44.. 51	COM[7:0]	O	LCD COMMon Output	Fill the data from D8H, refer LCD and RAM map.
4..43	SEG[39:0]	O	LCD SEGment Output	
53	LC2	B	Charge Pump Switch 1	Refer to application circuit.
52	LC1	B	Charge Pump Switch 2	
55	LV3	B	Charge Pump V3	Refer to application circuit.
54	LV1	B	Charge Pump V1	
56.. 59	LR[4..1]	B	LCD Resister level 4 ~ 0	Refer to application circuit.
60	LVG	I	LCD Virtual Ground	Refer to application circuit.
2	PWMP	O	PWM +ve O/P pin, can directly drive Speaker or Buzzer for voice output.	Preset the Bit2 of VOC register: PWM =1 ; turn on PWM.

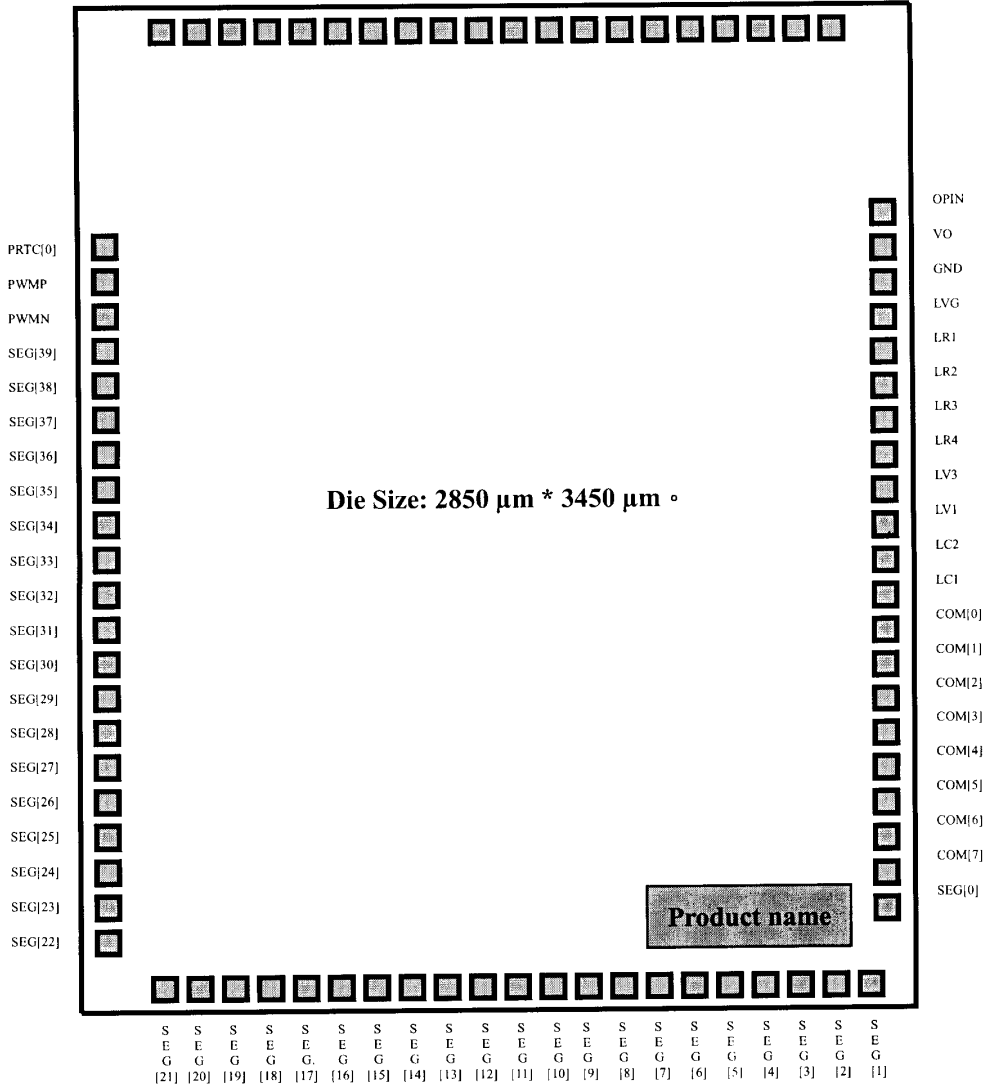
3	PWMN	O	PWM -ve O/P pin, can directly drive Speaker or Buzzer for voice output.	Preset the Bit2 of VOC register: PWM =1 ; turn on PWM.
62	VO	O	D/A voice output	Preset the Bit-1 of VOC register: DA=1 ; turn on VO.
63	OPIN	I	OPAMP Inverting I/P pin	Individual built-in OP-Amp
64	OPIP	I	OPAMP Non-inverting I/P pin.	
65	OPO	O	OPAMP O/P pin	
72	VDD	P	Positive Power Input	Adding 0.1µF capacitor as by-pass capacitor is between
61	GND	P	Power Ground Input	VDD and GND is necessary

E.LCD RAM Map

	SEG [7:0]	SEG [15:8]	SEG [23:16]	SEG [31:24]	SEG [39:32]
COM0	D8H	E0H	E8H	F0H	F8H
COM1	D9H	E1H	E9H	F1H	F9H
COM2	DAH	E2H	EAH	F2H	FAH
COM3	DBH	E3H	EBH	F3H	FBH
COM4	DCH	E4H	ECH	F4H	FCH
COM5	DDH	E5H	EDH	F5H	FDH
COM6	DEH	E6H	EEH	F6H	FEH
COM7	DFH	E7H	EFH	F7H	FFH

F. Pin Diagram

P	P	P	P	P	P	P	P	P	P	V	S	S	T	F	F	R	O	O
R	R	R	R	R	R	R	R	R	R	D	X	X	S	X	X	S	P	P
T	T	T	T	T	T	T	T	T	T	D	I	O	S	T	T	S	O	O
C	C	D	D	D	D	D	D	D	D				T	T	O	T		
[1]	[2]	[3]	[0]	[1]	[2]	[3]	[4]	[5]	[6]	[7]			P			N		P



G. Bonding Pad Location

PIN Number	PIN Name	X Coordinate	Y Coordinate	PIN Number	PIN Name	X Coordinate	Y Coordinate
1	PRTC[0]	X= -1339.50	Y= 905.20	43	SEG[0]	X= 1339.90	Y= -1302.80
2	PWMP	X= -1339.50	Y= 789.80	44	COM[7]	X= 1339.90	Y= -1187.20
3	PWMN	X= -1339.50	Y= 674.20	45	COM[6]	X= 1339.90	Y= -1071.80
4	SEG[39]	X= -1339.50	Y= 558.80	46	COM[5]	X= 1339.90	Y= -956.20
5	SEG[38]	X= -1339.50	Y= 443.20	47	COM[4]	X= 1339.90	Y= -840.80
6	SEG[37]	X= -1339.50	Y= 327.80	48	COM[3]	X= 1339.90	Y= -725.20
7	SEG[36]	X= -1339.50	Y= 212.20	49	COM[2]	X= 1339.90	Y= -609.80
8	SEG[35]	X= -1339.50	Y= 96.80	50	COM[1]	X= 1339.90	Y= -494.20
9	SEG[34]	X= -1339.50	Y= -18.80	51	COM[0]	X= 1339.90	Y= -378.80
10	SEG[33]	X= -1339.50	Y= -134.20	52	LC1	X= 1339.90	Y= -263.20
11	SEG[32]	X= -1339.50	Y= -249.80	53	LC2	X= 1339.90	Y= -147.80
12	SEG[31]	X= -1339.50	Y= -365.20	54	LV1	X= 1339.90	Y= -32.20
13	SEG[30]	X= -1339.50	Y= -480.80	55	LV3	X= 1339.90	Y= 83.20
14	SEG[29]	X= -1339.50	Y= -596.20	56	LR4	X= 1339.90	Y= 198.80
15	SEG[28]	X= -1339.50	Y= -711.80	57	LR3	X= 1339.90	Y= 314.20
16	SEG[27]	X= -1339.50	Y= -827.20	58	LR2	X= 1339.90	Y= 429.80
17	SEG[26]	X= -1339.50	Y= -942.80	59	LR1	X= 1339.90	Y= 545.20
18	SEG[25]	X= -1339.50	Y= -1058.20	60	LVG	X= 1339.90	Y= 660.80
19	SEG[24]	X= -1339.50	Y= -1173.80	61	GND	X= 1339.90	Y= 776.20
20	SEG[23]	X= -1339.50	Y= -1289.20	62	VO	X= 1339.90	Y= 891.80
21	SEG[22]	X= -1339.50	Y= -1404.80	63	OPIN	X= 1339.90	Y= 1007.20
22	SEG[21]	X= -1075.00	Y= -1641.00	64	OPIP	X= 1121.00	Y= 1639.60
23	SEG[20]	X= -959.50	Y= -1641.00	65	OPO	X= 1005.50	Y= 1639.60
24	SEG[19]	X= -844.00	Y= -1641.00	66	RSTP_N	X= 890.00	Y= 1639.60
25	SEG[18]	X= -728.50	Y= -1641.00	67	FXO	X= 774.50	Y= 1639.60
26	SEG[17]	X= -613.00	Y= -1641.00	68	FXT	X= 659.00	Y= 1639.60
27	SEG[16]	X= -497.60	Y= -1641.00	69	TSTP_P	X= 543.50	Y= 1639.60
28	SEG[15]	X= -382.10	Y= -1641.00	70	SXO	X= 428.10	Y= 1639.60
29	SEG[14]	X= -266.60	Y= -1641.00	71	SXI	X= 312.60	Y= 1639.60
30	SEG[13]	X= -151.10	Y= -1641.00	72	VDD	X= 197.10	Y= 1639.60
31	SEG[12]	X= -35.50	Y= -1641.00	73	PRTD[7]	X= 81.50	Y= 1639.60
32	SEG[11]	X= 80.00	Y= -1641.00	74	PRTD[6]	X= -34.00	Y= 1639.60
33	SEG[10]	X= 195.40	Y= -1641.00	75	PRTD[5]	X= -149.40	Y= 1639.60
34	SEG[9]	X= 310.90	Y= -1641.00	76	PRTD[4]	X= -264.90	Y= 1639.60
35	SEG[8]	X= 426.40	Y= -1641.00	77	PRTD[3]	X= -380.40	Y= 1639.60
36	SEG[7]	X= 542.00	Y= -1641.00	78	PRTD[2]	X= -495.90	Y= 1639.60
37	SEG[6]	X= 657.50	Y= -1641.00	79	PRTD[1]	X= -611.50	Y= 1639.60
38	SEG[5]	X= 773.00	Y= -1641.00	80	PRTD[0]	X= -727.00	Y= 1639.60
39	SEG[4]	X= 888.50	Y= -1641.00	81	PRTC[3]	X= -842.50	Y= 1639.60
40	SEG[3]	X= 1004.00	Y= -1641.00	82	PRTC[2]	X= -958.00	Y= 1639.60
41	SEG[2]	X= 1119.50	Y= -1641.00	83	PRTC[1]	X= -1073.50	Y= 1639.60
42	SEG[1]	X= 1235.00	Y= -1641.00				

H. Electrical Characteristics

Absolute Maximum Rating

Item	Sym.	Rating	Condition
Supply Voltage	V_{dd}	-0.5V ~ 8V	
Input Voltage	V_{in}	-0.5V ~ $V_{dd}+0.5V$	
Output Voltage	V_o	-0.5V ~ $V_{dd}+0.5V$	
Operating Temperature	T_{op}	0°C ~ 70°C	
Storage Temperature	T_{st}	-50°C ~ 100°C	

Recommended Operating Conditions

Item	Sym.	Rating	Condition
Supply Voltage	V_{dd}	2.4V ~ 5.2V	
Input Voltage	V_{ih}	0.9 V_{dd} ~ V_{dd}	
	V_{il}	0.0V ~ 0.1 V_{dd}	
Operating Frequency	Fmax	8MHz	$V_{dd}=5.0V$
		4MHz	$V_{dd}=2.4V$
Operating Temperature	T_{op}	0°C ~ 70°C	
Storage Temperature	T_{st}	-50°C ~ 100°C	

Test condition:TEMP=25°C, VDD=3V+/-10%, GND=0V

	PARAMETER		CONDITION	MIN	TYP	MAX	UNIT
I_{Fast}	NORMAL Mode Current	System	2M ext. R/C		0.75	1	mA
I_{Slow}	SLOW Mode Current	System	32.768K X'tal LCD Disable		10	20	μA
I_{Idle}	IDLE Mode Current	System	32.769K X'tal LCD Disable		6	10	μA
I_{LCD}	Extra Current if LCD ON	System	LCD Enable, LCD option=300Kohm Voltage-doubler OFF		12	20	μA
			LCD Enable, LCD option=30Kohm, Voltage-doubler ON		100	120	
I_{Sleep}	Sleep Mode Current	System				1	μA
I_{oHPW}	PWM Output Drive Current	PWMP, PWMN*2	$V_{DD}=3V; V_{oh}=2V$	12	15		mA
I_{oLPW}	PWM Output Sink Current	PWMP, PWMN*2	$V_{DD}=3V; V_{ol}=1V$	33	40		mA
I_{ovo}	DAC Output Current	VO	$V_{DD}=3V; VO=0\sim 2V, Data=7F$	2.5	3		mA
V_{ih}	Input High Voltage	I/O pins		0.8			V
				V_{DD}			
V_{il}	Input Low Voltage	I/O pins				0.2	V
						V_{DD}	
V_{hys}	Input Hysteresis Width	I/O, RSTP_N	Threshold= $2/3V_{DD}$ (input from low to high) Threshold= $1/3V_{DD}$ (input from high to low)		1/3		V
					V_{DD}		
I_{oh}	Output Drive Current	I/O pull-high*1	$V_{ol}=2.0V$	50			μA
I_{ol1}	Output Sink Current	I/O pull-low*1	$V_{ol}=0.4V$	1.0			mA
I_{il1}	Input Low Current	RSTP_N	$V_{il}=GND$, pull high Internally		20		μA
I_{il2}	Input Low Current	I/O	$V_{il}=GND$, if pull high Internally by user		100		μA

Note: *1: Drive Current Spec. for Push-Pull I/O port only

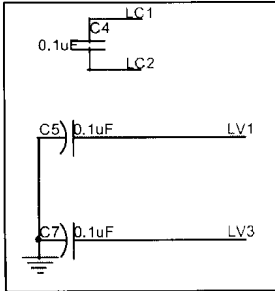
Sink Current Spec. for both Push-Pull and Open-Drain I/O port.

*2: This Spec. base on one driver only. There are five build-in driver, so user just multiply the number of driver he used to one driver current

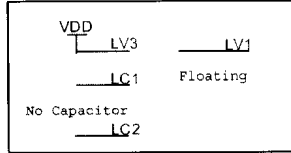
to get the total amount of current. ($I_{oHPWM} \cdot I_{oLPWM} * N$; N=0,1,2,3,4,5)

I. Application Circuit

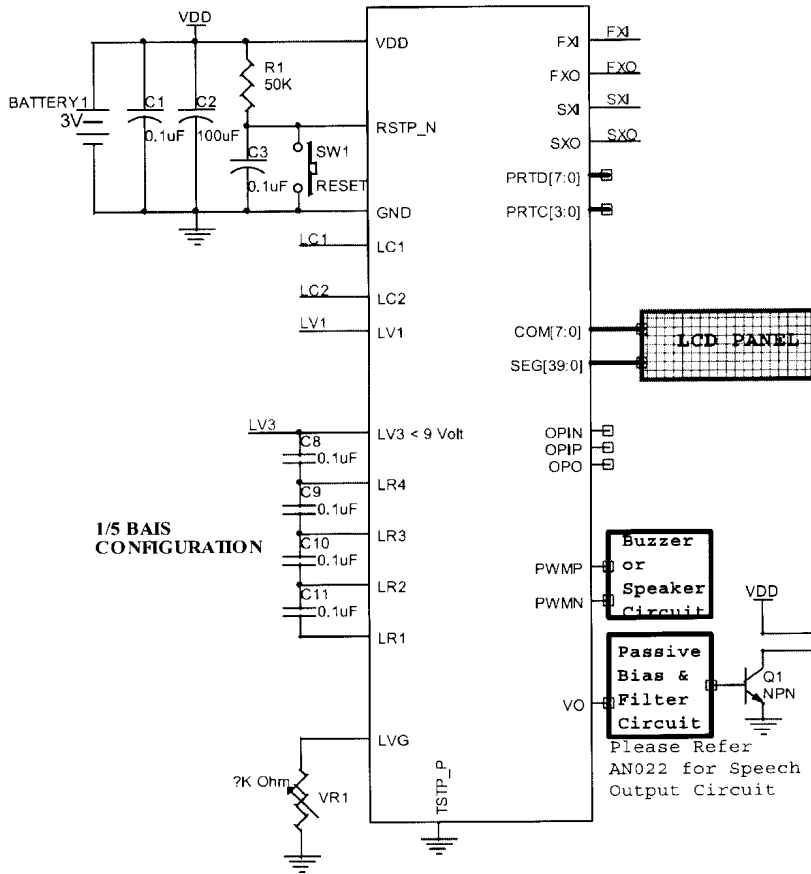
Tripple Charge Pump is selected
 LCD Max. Voltage=LV3=3/2*VDD



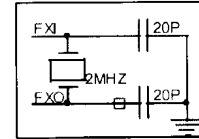
Tripple Charge Pump is selected
 LCD Max. Voltage=LV3=VDD



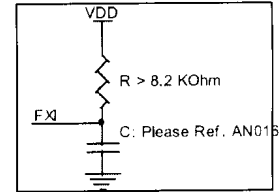
No External Parts is necessary if user adopt Internal Fast RC Clock



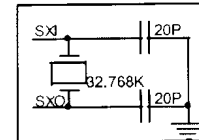
External Fast Clock:
 Crystal osc.



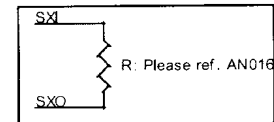
External Fast Clock:
 RC osc.



External Slow Clock:
 Crystal osc.



External Slow Clock:
 RC osc.

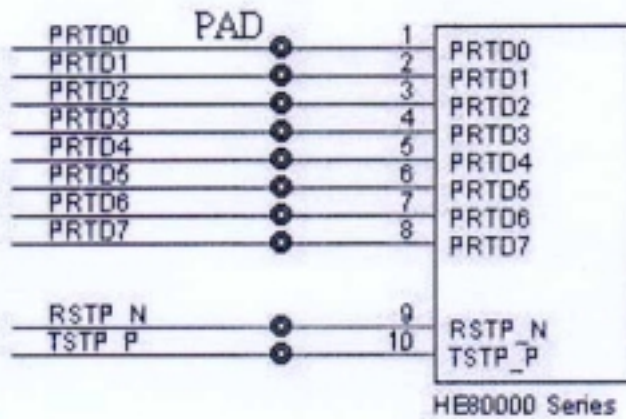


J. Important Note

For accessing any address large than 64KB, users must update TPP first, TPH then TPL. Only by this order, the pre-charge circuit of ROM will work correctly. 5us waiting is necessary before LDV instruction is executed since Data ROM is a low speed ROM. Users can not emulate this accessing process in ICE. So 5us delay should be added by firmware.

LCD driving circuit must be turn off before IC goes into sleep mode

Please bonds the TSTP_P, RSTP_N and PRTD[7:0] with test point on PCB (can be soldered and probed) as you can, then JESS can do some IC testing job on PCB. Neither VDD nor GND connection is necessary for TSTP_P. The following figure is an example (Testing point with through hole.)



LV3 must small than 9.0 Volt. Otherwise IC may breakdown.

SUPPLEMENTARY SPECIFICATION: HE82/83/89 PWM application

Description:

For HE83/89 PWM application, the following points must be bare in mind.

1. The PWM output can direct drive buzzer.
2. For direct drive speaker, it must use 32Ω or above speaker.
3. For speaker application, it must add capacitors between IC's VDD ground and its PWM output, see below figure.

Note: the $1\mu\text{F}$ capacitor must be connected near IC's

